Vishay Semiconductors

Ultrafast Rectifier, 15 A FRED Pt[®]



www.vishay.com

TO-220 FullPAK 2L

PRIMARY CHARACTERISTICS					
I _{F(AV)}	15 A				
V _R	600 V				
V _F at I _F	1.1 V				
t _{rr} (typ.)	24 ns				
T _J max.	175 °C				
Package	TO-220 FullPAK 2L				
Circuit configuration	Single				

FEATURES

- Low forward voltage drop
- · Ultrafast soft recovery time
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- True 2 pin package
- Designed and qualified according to JEDEC[®]-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

State of the art, ultralow V_F, soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V _{RRM}		600	V
Average rectified forward current in DC	I _{F(AV)}	T _C = 103 °C	15	٨
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \ ^{\circ}C$	160	A
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	600	-	-		
Forward voltage		I _F = 15 A	-	1.35	1.9	V	
Forward voltage V _F		I _F = 15 A, T _J = 150 °C	-	1.1	1.3		
Reverse leakage current	I_	$V_R = V_R$ rated	-	0.01	15	μA	
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	20	200	μΑ	
Junction capacitance	CT	V _R = 600 V	-	12	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	

Revision: 28-Feb-2023 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000

Document Number: 93534

RoHS COMPLIANT HALOGEN FREE



www.vishay.com

Vishay Semiconductors

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 100$	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$			28	
Reverse recovery time	+	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 10$	00 A/µs, V _R = 30 V	-	36	47	ns
Reverse recovery time	t _{rr}	T _J = 25 °C		-	40	-	
		T _J = 125 °C	I _F = 15 A, dI _F /dt = 200 A/μs, V _R = 390 V	-	87	-	
Peak recovery current	1	T _J = 25 °C		-	5	-	A
Feak recovery current	I _{RRM}	T _J = 125 °C		-	9	-	
Powerze recovery charge	0	T _J = 25 °C		-	107	-	nC
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	430	-	
Reverse recovery time	t _{rr}		I _F = 15 A, dI _F /dt = 800 A/μs,	-	53	-	ns
Peak recovery current	I _{RRM}	T _J = 125 °C		-	25	-	А
Reverse recovery charge	Qrr		V _R = 390 V	-	730	-	nC

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C		
Thermal resistance, junction-to-case	R _{thJC}		-	3.7	4.3			
Thermal resistance, junction-to-ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W		
Typical thermal resistance, case-to-heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-			
Weight			-	2	-	g		
Weight			-	0.07	-	oz.		
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style TO-220 FullPAK 2L		ETU1	506FP			



VS-ETU1506FP-M3

Vishay Semiconductors

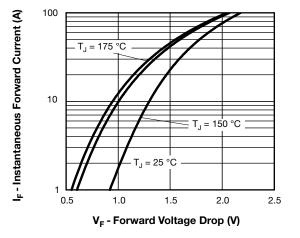


Fig. 1 - Typical Forward Voltage Drop Characteristics

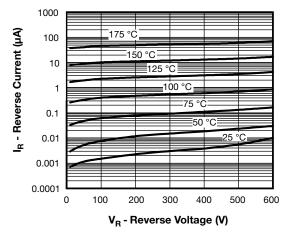


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

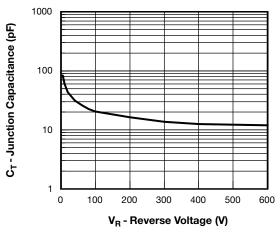


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

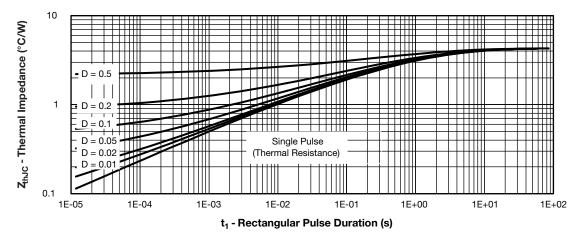


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

 Revision: 28-Feb-2023
 3
 Document Number: 93534

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



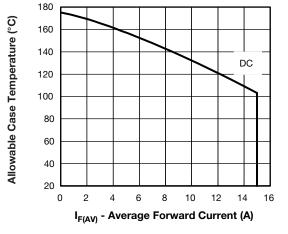


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

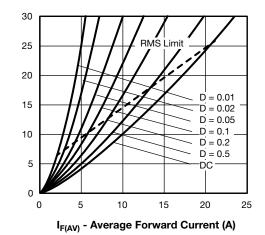
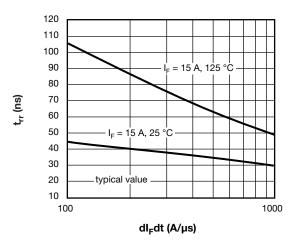


Fig. 6 - Forward Power Loss Characteristics



VS-ETU1506FP-M3

Vishay Semiconductors

Fig. 7 - Typical Reverse Recovery vs. dl_F/dt

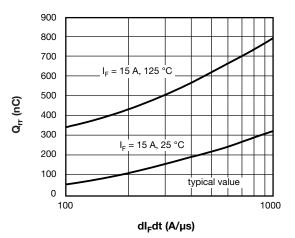


Fig. 8 - Typical Stored Charge vs. dl_F/dt

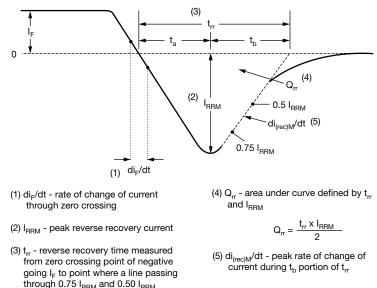


Fig. 9 - Reverse Recovery Waveform and Definitions

extrapolated to zero current.

((2) I _R	Q _{rr} ⁽⁴⁾ 0.5 I _{RRM} di _{(rec)M} /dt (5)	
(1) di _F /dt - rate of change through zero crossing		(4) ${\rm Q}_{\rm rr}$ - area under curve defined by ${\rm t}_{\rm rr}$ and ${\rm I}_{\rm RBM}$	
(2) I _{RRM} - peak reverse re	covery current	$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$	
(3) t _{rr} - reverse recovery t from zero crossing po going I _F to point wher through 0.75 I _{BRM} and	int of negative e a line passing	(5) di _{(rec)M} /dt - peak rate of change of current during t _b portion of t _{rr}	

Revision: 28-Feb-2023 Document Number: 93534 4 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

Vishay Semiconductors

ORDERING INFORMATION TABLE

www.vishay.com

VISHAY

Device code	VS-	Е	т	U	15	06	FP	-M3
		2	3	4	5	6	$\overline{7}$	8
	1 -	- Visl	nay Sen	niconduo	ctors pro	oduct		
	2 -	Circ	uit conf	iguratior	י.			
		E =	single					
	3 -	• T =	TO-220)				
	4 -	• U =	hyperfa	ist recov	very time	Э		
	5 -	- Cur	rent coc	le: 15 =	15 A			
	6 -	· Volt	age coo	de: 06 =	600 V			
	7 -	FP	= TO-22	20 FullP	AK 2L			
	8 -	- Env	ironmer	ntal digit	:			
		-M3	s = halog	gen-free	, RoHS	-complia	ant, and	termina

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-ETU1506FP-M3	50	1000	Antistatic plastic tube				

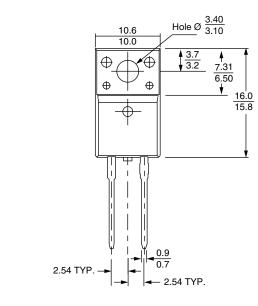
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96157				
Part marking information	www.vishay.com/doc?95392				
SPICE model	www.vishay.com/doc?96131				

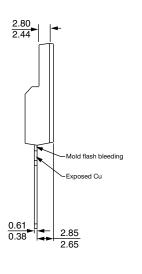


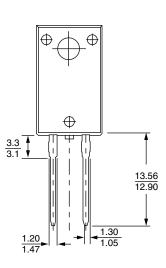
Vishay Semiconductors

2L TO-220 FullPAK

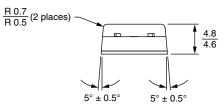
DIMENSIONS in millimeters







Bottom view





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.